

SCOPE OF CLAIMED INVENTION:

1. A semiconductor device characterized in comprising:
 - a first semiconductor chip mounted on a substrate;
 - a second semiconductor chip mounted on the first semiconductor chip, the second semiconductor chip being larger than the first semiconductor chip;
 - a base member that is disposed between the second semiconductor chip and the substrate; and
 - a connection member disposed below the substrate,wherein the second semiconductor chip is supported by the base member.
2. A semiconductor device characterized in comprising:
 - a first semiconductor chip mounted on a substrate;
 - a second semiconductor chip mounted on the first semiconductor chip, the second semiconductor chip being larger than the first semiconductor chip;
 - a filler layer that is provided between the second semiconductor chip and the substrate; and
 - a connection member disposed below the substrate,wherein the second semiconductor chip is supported by the filler layer.
3. A method for manufacturing a semiconductor device, the method characterized in comprising the steps of:
 - mounting a first semiconductor chip on a substrate;
 - mounting a base member outside the first semiconductor chip on the substrate; and
 - mounting a second semiconductor chip that is larger than the first semiconductor chip on the first semiconductor chip, in a manner that the second semiconductor chip is supported by the base member.

4. A method for manufacturing a semiconductor device, the method characterized in comprising the steps of:

- mounting a first semiconductor chip on a substrate,
- mounting a second semiconductor chip that is larger than the first semiconductor chip on the first semiconductor chip; and
- providing a filler layer in a manner to support the second semiconductor chip.